

# Scaling the Nanoimprint Lithography Process of Inorganic-Based Materials

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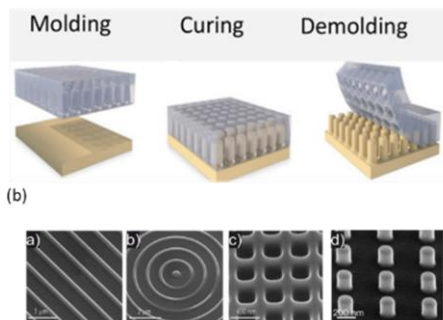
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Nanoimprint lithography (NIL) is a method to (nano-) structure inorganic materials from sol-gel liquid formulations and colloidal suspensions onto a surface [1]. This technique, first inspired by embossing techniques, was developed for soft polymer processing, as final or intermediate materials, but is today fully adapted to hard, inorganic materials with a high dielectric constant, such as metal oxides, with countless chemical compositions provided by the sol-gel chemistry. Consequently, NIL has become a versatile, high-throughput, and highly precise fabrication method that is mature for scaling up. In my presentation I will first describe generalities of sol-gel dip-coating and NIL method for metal oxides (e.g. SiO<sub>2</sub>, TiO<sub>2</sub>, ZrO<sub>2</sub>) showing the possibility to form high refractive index materials (n up to 2.65 for dense TiO<sub>2</sub>). Then, I will review some of the recent results we obtained in this field, including fabrication of ordered and disordered optical metasurfaces [2], structural color [3], anti-reflection coatings [4] on flat and curved surfaces, refractive index sensing [5], light emission and enhanced light extraction [6]. Finally, I will show that the method can be scaled up to 200 mm wafers on Si and glass to print ordered and disordered patterns.

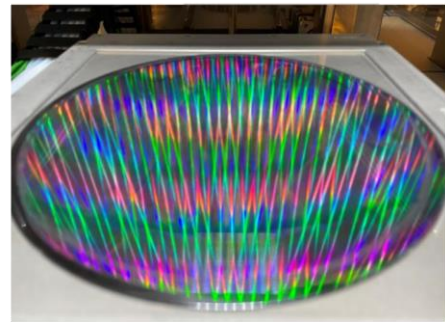
Top: basic principle of NIL. Bottom: examples of metal-oxides structures obtained via NIL



Gratings of SiO<sub>2</sub> printed atop curved surfaces (lenses)



Example of SiO<sub>2</sub> pillars printed on a 200 mm Si wafer with a semi-industrial Obducat machine.



- [1] M. Modaresialam et al., *Chemistry of Materials* 33 (14), 5464 (2021)
- [2] Z. Chehadi et al., *ACS Applied Materials & Interfaces* 13 (31), 37761 (2021)
- [3] S. Checcucci et al., *Advanced Optical Materials* 7 (10), 1801406 (2019)
- [4] M. Modaresialam et al., *ACS Applied Nano Materials* 3 (6), 5231 (2020)
- [5] M. Modaresialam et al., *ACS Applied Materials & Interfaces* 13 (44), 53021 (2021)
- [6] Z. Chehadi et al., *Advanced Optical Materials* 10 (21), 2201618 (2022)